

SINGLE BUFFER/DRIVER WITH OPEN-DRAIN OUTPUT

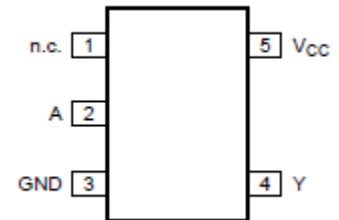
1、 General Description

The 74LVC1G07 provides the non-inverting buffer.

The output of this device is an open drain and can be connected to other open-drain outputs to implement active-LOW wired-OR or active-HIGH wired-AND functions.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device in a mixed 3.3V and 5V environment.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.



Features:

- Wide supply voltage range from 1.65V to 5.5V
- 5V tolerant inputs for interfacing with 5V logic -
- 24mA output drive ($V_{CC}=3.0V$)
- CMOS low power consumption
- Latch-up performance exceeds 250mA
- Direct interface with TTL levels
- Input accepts voltages up to 5V
- Specified from $-40^{\circ}C$ to $+105^{\circ}C$
- Packaging information: DBVR SOT-23-5/
DCKR SOT-353

2、 Block Diagram And Pin Description

2.1、 Block Diagram

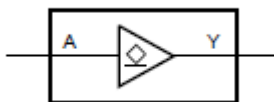


Figure 1. Logic symbol

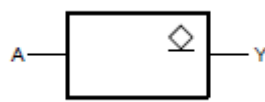


Figure 2. IEC logic symbol

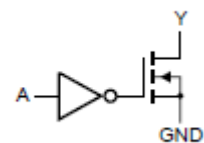
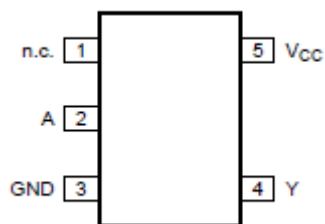


Figure 3. Logic diagram

2.2、 Pin Configurations



2.3、 Pin Description

Pin No.	Pin Name	Description
1	n.c.	not connected
2	A	data input
3	GND	ground (0V)
4	Y	data output
5	V _{CC}	supply voltage

2.4、 Function Table

Input	Output
A	Y
L	L
H	Z

Note: H=HIGH voltage level; L=LOW voltage level; Z=high-impedance OFF-state.

3、Electrical Parameter

3.1、Absolute Maximum Ratings

(Voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Max.	Unit
supply voltage	V_{CC}	-	-0.5	+6.5	V
input clamping current	I_{IK}	$V_I < 0V$	-50	-	mA
input voltage	V_I	-	-0.5	+6.5	V
output clamping current	I_{OK}	$V_O < 0V$	-50	-	mA
output voltage	V_O	Active mode	-0.5	+6.5	V
		Power-down mode; $V_{CC}=0V$	-0.5	+6.5	V
output current	I_O	$V_O=0V$ to V_{CC}	-	50	mA
supply current	I_{CC}	-	-	100	mA
ground current	I_{GND}	-	-100	-	mA
storage temperature	T_{stg}	-	-65	+150	°C
total power dissipation	P_{tot}	-	-	250	mW
Soldering temperature	T_L	10s	250		°C

3.2、Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{CC}	-	1.65	-	5.5	V
input voltage	V_I	-	0	-	5.5	V
output voltage	V_O	Active mode	0	-	5.5	V
		Power-down mode; $V_{CC}=0V$	0	-	5.5	V
ambient temperature	T_{amb}	-	-40	-	+105	°C
input transition rise and fall rate	$\Delta t/\Delta V$	$V_{CC}=1.65V$ to $2.7V$	-	-	20	ns/V
		$V_{CC}=2.7V$ to $5.5V$	-	-	10	ns/V

3.3、Electrical Characteristics

3.3.1、DC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V _{IH}	V _{CC} =1.65V to 1.95V		0.65× V _{CC}	-	-	V
		V _{CC} =2.3V to 2.7V		1.7	-	-	V
		V _{CC} =2.7V to 3.6V		2.0	-	-	V
		V _{CC} =4.5V to 5.5V		0.7× V _{CC}	-	-	V
LOW-level input voltage	V _{IL}	V _{CC} =1.65V to 1.95V		-	-	0.35× V _{CC}	V
		V _{CC} =2.3V to 2.7V		-	-	0.7	V
		V _{CC} =2.7V to 3.6V		-	-	0.8	V
		V _{CC} =4.5V to 5.5V		-	-	0.3× V _{CC}	V
LOW-level output voltage	V _{OL}	V _I = V _{IH} or V _{IL}	I _O =100uA; V _{CC} =1.65V to 5.5V	-	-	0.1	V
			I _O =4mA; V _{CC} =1.65V	-	-	0.45	V
			I _O =8mA; V _{CC} =2.3V	-	-	0.3	V
			I _O =12mA; V _{CC} =2.7V	-	-	0.4	V
			I _O =24mA; V _{CC} =3.0V	-	-	0.55	V
			I _O =32mA; V _{CC} =4.5V	-	-	0.55	V
input leakage current	I _I	V _I =5.5V or GND; V _{CC} =0V to 5.5V		-	±0.1	±1	uA
OFF-state output current	I _{OZ}	V _I =V _{IH} or V _{IL} ; V _O =V _{CC} or GND; V _{CC} =5.5V		-	±0.1	±2	uA
power-off leakage current	I _{OFF}	V _I or V _O =5.5V; V _{CC} =0V		-	±0.1	±2	uA
supply current	I _{CC}	V _I =5.5V or GND; I _O =0A; V _{CC} =1.65V to 5.5V		-	0.1	4	uA
additional supply current	ΔI _{CC}	per pin; V _I =V _{CC} -0.6V; I _O =0A; V _{CC} =2.3V to 5.5V		-	5	500	uA
input capacitance	C _I	V _{CC} =3.3V; V _I =GND to V _{CC}		-	5	-	pF

Note: All typical values are measured at $V_{CC}=3.3\text{V}$ and $T_{amb}=25^{\circ}\text{C}$.

3.3.2、DC Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+105^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V_{IH}	$V_{CC}=1.65\text{V}$ to 1.95V		$0.65 \times V_{CC}$	-	-	V
		$V_{CC}=2.3\text{V}$ to 2.7V		1.7	-	-	V
		$V_{CC}=2.7\text{V}$ to 3.6V		2.0	-	-	V
		$V_{CC}=4.5\text{V}$ to 5.5V		$0.7 \times V_{CC}$	-	-	V
LOW-level input voltage	V_{IL}	$V_{CC}=1.65\text{V}$ to 1.95V		-	-	$0.35 \times V_{CC}$	V
		$V_{CC}=2.3\text{V}$ to 2.7V		-	-	0.7	V
		$V_{CC}=2.7\text{V}$ to 3.6V		-	-	0.8	V
		$V_{CC}=4.5\text{V}$ to 5.5V		-	-	$0.3 \times V_{CC}$	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH}$ or V_{IL}	$I_O=100\mu\text{A}; V_{CC}=1.65\text{V}$ to 5.5V	-	-	0.1	V
			$I_O=4\text{mA}; V_{CC}=1.65\text{V}$	-	-	0.7	V
			$I_O=8\text{mA}; V_{CC}=2.3\text{V}$	-	-	0.45	V
			$I_O=12\text{mA}; V_{CC}=2.7\text{V}$	-	-	0.6	V
			$I_O=24\text{mA}; V_{CC}=3.0\text{V}$	-	-	0.8	V
			$I_O=32\text{mA}; V_{CC}=4.5\text{V}$	-	-	0.8	V
input leakage current	I_I	$V_I=5.5\text{V}$ or GND; $V_{CC}=0\text{V}$ to 5.5V		-	-	± 1	μA
OFF-state output current	I_{OZ}	$V_I=V_{IH}$ or $V_{IL}; V_O=V_{CC}$ or GND; $V_{CC}=5.5\text{V}$		-	-	± 2	μA
power-off leakage current	I_{OFF}	V_I or $V_O=5.5\text{V}; V_{CC}=0\text{V}$		-	-	± 2	μA
supply current	I_{CC}	$V_I=5.5\text{V}$ or GND; $I_O=0\text{A}; V_{CC}=1.65\text{V}$ to 5.5V		-	-	4	μA
additional supply current	ΔI_{CC}	per pin; $V_I=V_{CC}-0.6\text{V}; I_O=0\text{A}; V_{CC}=2.3\text{V}$ to 5.5V		-	-	500	μA

Note: All typical values are measured at $V_{CC}=3.3\text{V}$ and $T_{amb}=25^{\circ}\text{C}$.

3.3.3、 AC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
A to Y propagation delay	t_{pd}	see Figure 5	$V_{CC}=1.65V$ to $1.95V$	1.0	2.6	6.7	ns
			$V_{CC}=2.3V$ to $2.7V$	0.5	1.7	5.5	ns
			$V_{CC}=2.7V$	0.5	2.3	4.7	ns
			$V_{CC}=3.0V$ to $3.6V$	0.5	2.2	4.2	ns
			$V_{CC}=4.5V$ to $5.5V$	0.5	1.6	3.5	ns
Power dissipation capacitance	C_{PD}	$V_{CC}=3.3V$; $V_I=GND$ to V_{CC}		-	7.0	-	pF

Note:

[1] Typical values are measured at $T_{amb}=25^{\circ}\text{C}$ and $V_{CC}=1.8\text{V}, 2.5\text{V}, 2.7\text{V}, 3.3\text{V}$ and 5.0V respectively.

[2] t_{pd} is the same as t_{PLZ} and t_{PZL} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = (C_{PD} \times V_{CC}^2 \times f_i \times N) + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i =input frequency in MHz;

f_o =output frequency in MHz;

C_L =output load capacitance in pF;

V_{CC} =supply voltage in V;

N =number of inputs switching;

$\sum (C_L \times V_{CC}^2 \times f_o)$ =sum of outputs.

3.3.4、 AC Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+105^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
A to Y propagation delay	t _{pd}	see Figure 5	V _{CC} =1.65V to 1.95V	1.0	-	8.4	ns
			V _{CC} =2.3V to 2.7V	0.5	-	7.0	ns
			V _{CC} =2.7V	0.5	-	6.0	ns
			V _{CC} =3.0V to 3.6V	0.5	-	5.5	ns
			V _{CC} =4.5V to 5.5V	0.5	-	4.5	ns

Note:

[1] Typical values are measured at $T_{amb}=25^{\circ}\text{C}$ and $V_{CC}=1.8\text{V}, 2.5\text{V}, 2.7\text{V}, 3.3\text{V}$ and 5.0V respectively.

[2] t_{pd} is the same as t_{PLZ} and t_{PZL} .

4、 Testing Circuit

4.1、 AC Testing Circuit

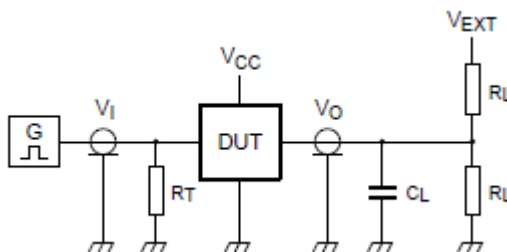


Figure 4. Test circuit for measuring switching times

Definitions for test circuit:

R_L =Load resistance.

C_L =Load capacitance including jig and probe capacitance.

R_T =Termination resistance; should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} =External voltage for measuring switching times.

4.2、 AC Testing Waveforms

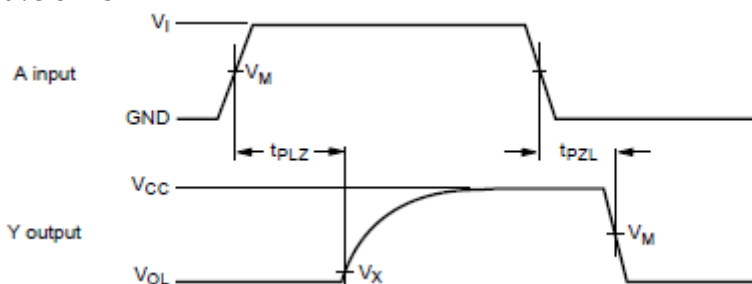


Figure 5. The input A to output Y propagation delays

4.3、 Measurement Points

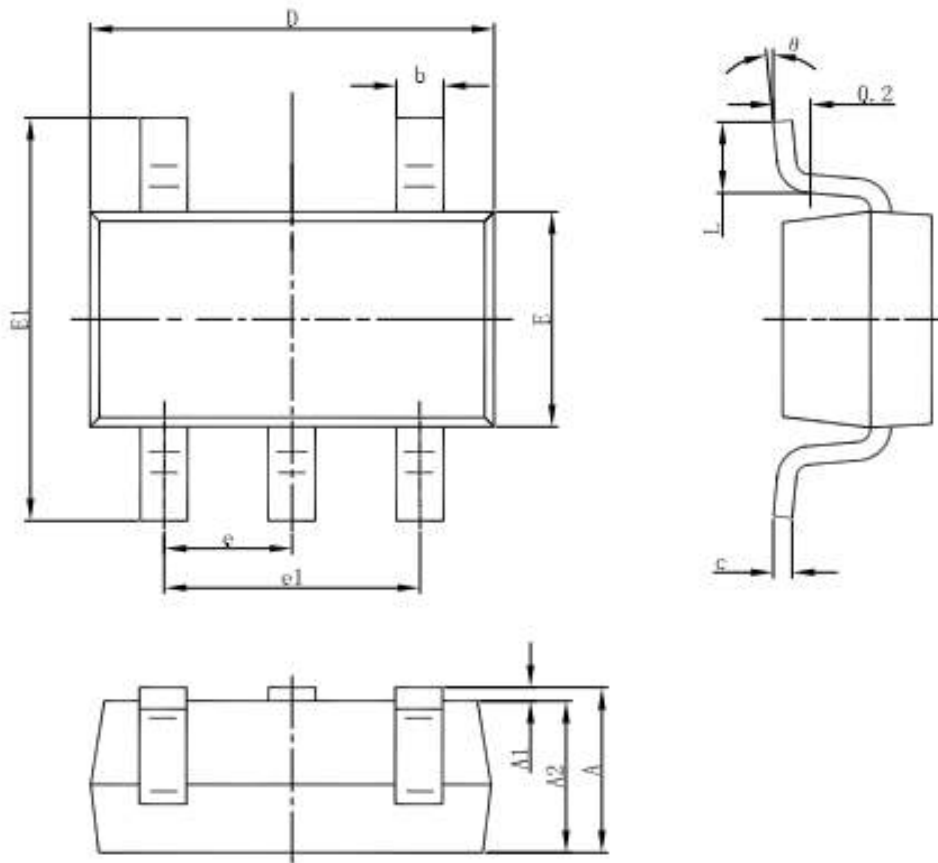
Supply voltage	Input	Output	
V_{CC}	V_M	V_M	V_X
1.65V to 1.95V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.15V$
2.3V to 2.7V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.15V$
2.7V	1.5V	1.5V	$V_{OL} + 0.3V$
3.0V to 3.6V	1.5V	1.5V	$V_{OL} + 0.3V$
4.5V to 5.5V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.3V$

4.4、 Test Data

Supply voltage	Input		Load		V_{EXT}
V_{CC}	V_I	t_r, t_f	C_L	R_L	t_{PLZ}, t_{PZL}
1.65V to 1.95V	V_{CC}	$\leq 2.0ns$	30pF	1k Ω	$2 \times V_{CC}$
2.3V to 2.7V	V_{CC}	$\leq 2.0ns$	30pF	500 Ω	$2 \times V_{CC}$
2.7V	2.7V	$\leq 2.5ns$	50pF	500 Ω	6V
3.0V to 3.6V	2.7V	$\leq 2.5ns$	50pF	500 Ω	6V
4.5V to 5.5V	V_{CC}	$\leq 2.5ns$	50pF	500 Ω	$2 \times V_{CC}$

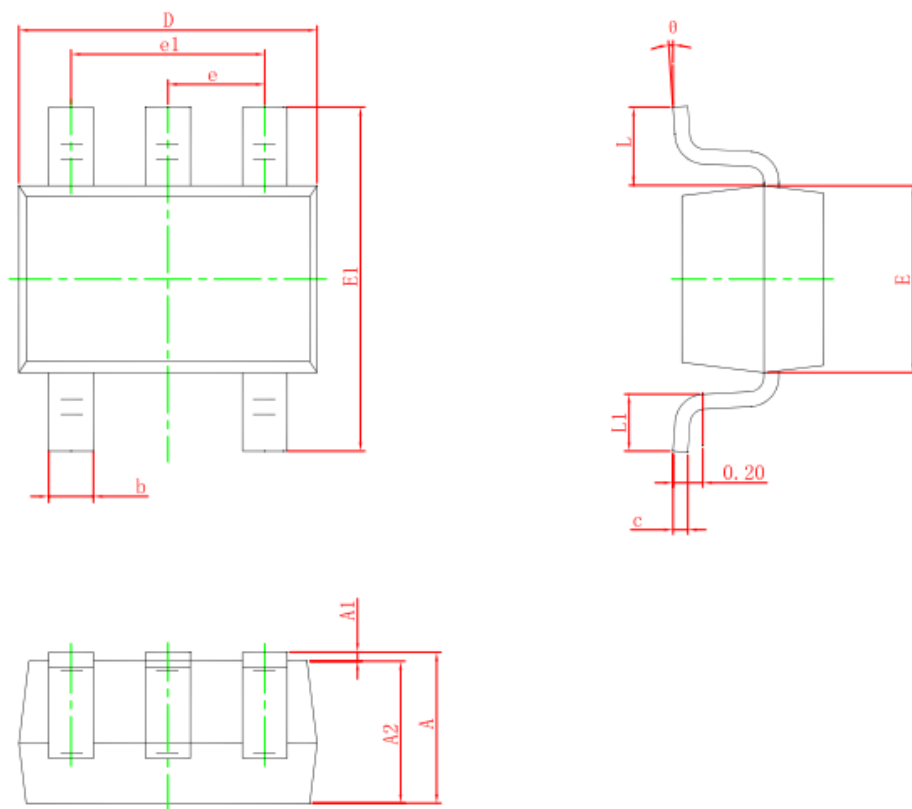
5、 Package Information

5.1、 SOT-23-5



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

5.2、SOT-353



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP.		0.026 TYP.	
e1	1.200	1.400	0.047	0.055
L	0.525 REF.		0.021 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°